



30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

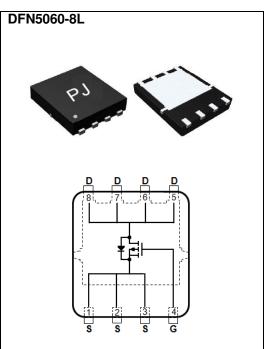
-30A

Features

- R_{DS(ON)}, V_{GS}@-10V,I_D@-8A<20mΩ
- $R_{DS(ON)}$, V_{GS} @-4.5V, I_D @-6A<32 $m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: DFN5060-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0028 ounces, 0.08 grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage Gate-Source Voltage		V _{DS}	-30 <u>+</u> 20	V
				V
Continuous Drain Current	T _C =25°C	- I _D	-30	
	T _C =100°C		-19	Α
Pulsed Drain Current(Note 1)	T _C =25°C	I _{DM}	-120	
Power Dissipation	T _C =25°C	Po	27	\A/
	T _C =100°C		11	W
Continuous Drain Current	T _A =25°C	I _D	-8.5	
	T _A =70°C		-6.9	A
Power Dissipation	T _A =25°C	0	2.0	147
Power Dissipation	T _A =70°C	Po	1.3	W
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	R _{0JC}	4.6	°C/A/
	Junction to Ambient	$R_{\theta JA}$	62.5	°C/W

Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =-250uA	-30	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250uA$	-1	-1.5	-2.5		
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} =-10V, I_D =-8A	-	17	20	mΩ	
		V _{GS} =-4.5V,I _D =-6A	-	26	32		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-30V, V_{GS} =0V	-	-	-1.0	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 6)							
Total Gate Charge	Q_g	V _{DS} =-15V, I _D =-5A, V _{GS} =-4.5V (Note 1,2)	-	11	-	nC	
Gate-Source Charge	Q_gs		-	3.2	-		
Gate-Drain Charge	Q_gd	V _{GS} =-4.5 V	-	3.9	-		
Input Capacitance	Ciss	V _{DS} =-15V, V _{GS} =0V,	-	1169	-	pF	
Output Capacitance	Coss	v _{DS} =-15v, v _{GS} =0v, f=1.0MHZ	-	180	-		
Reverse Transfer Capacitance	Crss	I=I.UIVINZ	-	132	-		
Turn-On Delay Time	td _(on)	\/ 45\/ 46	-	5.9	-		
Turn-On Rise Time	t _r	$V_{DS}=-15V, I_{D}=-1A,$ $V_{GS}=-10V, R_{G}=6\Omega$	-	33	-	ns	
Turn-Off Delay Time	td _(off)	(Note 1,2)	-	55	-		
Turn-Off Fall Time	t _f		-	34	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	,		-	-	-30	Α	
Diode Forward Current	I _S						
Diode Forward Voltage	V_{SD}	I _S =-1A,V _{GS} =0V	-	-0.73	-1	V	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing





TYPICAL CHARACTERISTIC CURVES

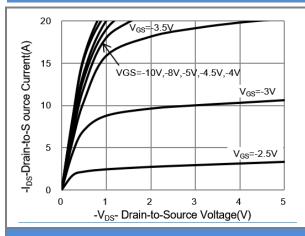


Fig.1 On-Region Characteristics

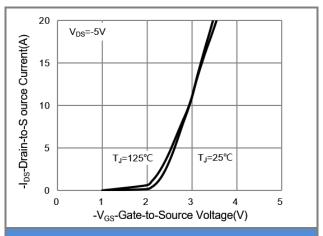


Fig.2 Transfer Characteristics

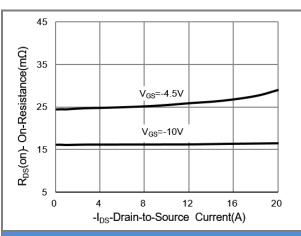


Fig.3 On-Resistance vs. Drain Current

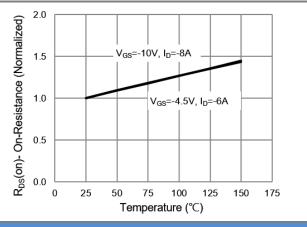


Fig.4 On-Resistance vs. Junction temperature

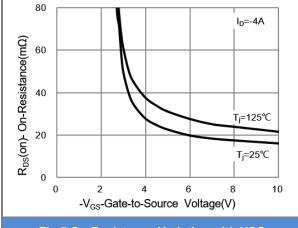
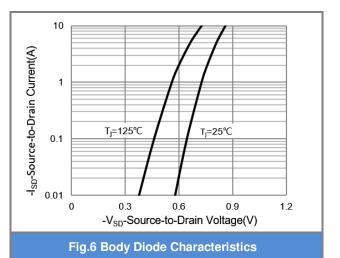


Fig.5 On-Resistance Variation with VGS.







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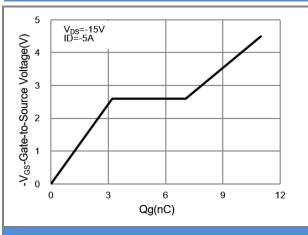


Fig.7 Gate-Charge Characteristics

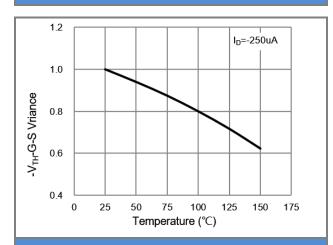
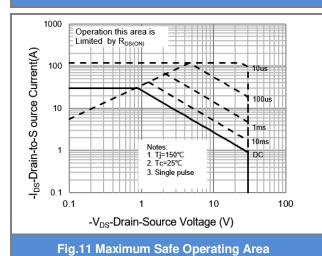


Fig.9 Threshold Voltage Variation with Temperature.



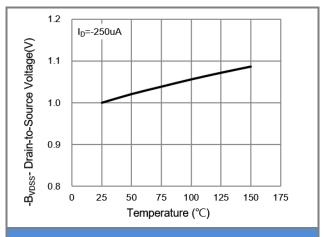


Fig.8 Breakdown Voltage Variation vs. Temperature

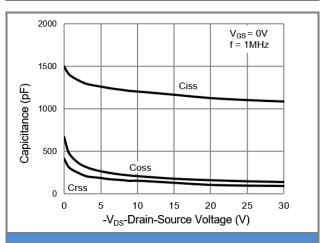


Fig.10 Capacitance vs. Drain-Source Voltage.





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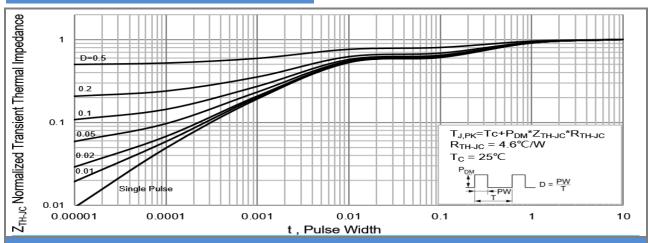


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

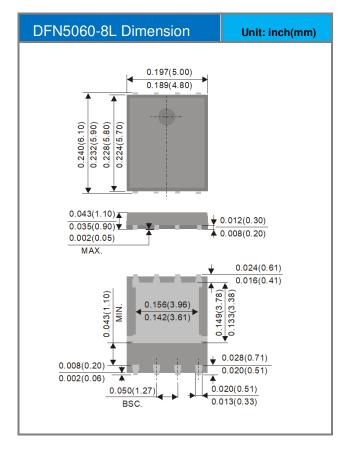


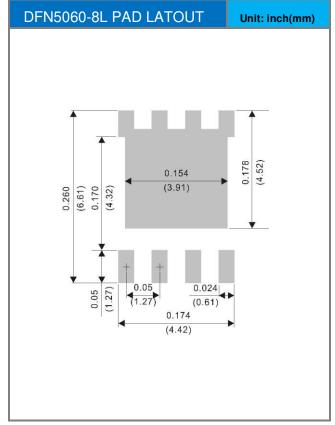


Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version	
PJQ5419_R2_00001	DFN5060-8L	3000pcs / 13" reel	Q5419	Halogen free	

Packaging Information & Mounting Pad Layout









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